

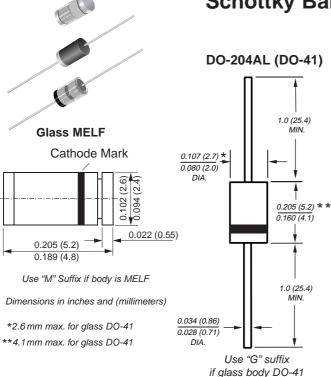


1N5817 thru 1N5819

Vishay Semiconductors formerly General Semiconductor

Schottky Barrier Rectifiers

Reverse Voltage 20 to 40V Forward Current 1.0A



Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Low power loss, high efficiency
- For use in low voltage high frequency inverters, free wheeling, and polarity protection applications
- · Guardring for overvoltage protection

Mechanical Data

Case: JEDEC DO-204 AL molded plastic body, glass

body or glass MELF body

Terminals: Plated leads, solderable per

MIL-STD-750, Method 2026

High temperature soldering guaranteed: 250°C/10 seconds at terminals for MELF and 0.375" (9.5mm) lead

length, 5lbs (2.3kg) tension for axials **Polarity:** Color band denotes cathode end

(band is green on MELF)

Weight: plastic body DO-41: 0.34g glass body DO-41: 0.35g glass MELF: 0.25g

Maximum Ratings and Thermal Characteristics (TA = 25°C unless otherwise noted)

Parameter	Symbol	1N5817	1N5818	1N5819	Unit
* Maximum repetitive peak reverse voltage	Vrrm	20	30	40	V
Maximum RMS voltage	VRMS	14	21	28	V
* Maximum DC blocking voltage	VDC	20	30	40	V
* Maximum non-repetitive peak reverse voltage	VRSM	24	36	48	V
* Maximum average forward rectified current 0.375" (9.5mm) lead length at T _L =90°C	I _{F(AV)}	1.0			А
* Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) at TL=70°C	IFSM		А		
Typical thermal resistance – junction-to-ambient (glass) (Note 2) – junction-to-ambient (plastic) – junction-to-lead (plastic)	Roja Roja Rojl	130 50 15			°C/W
*Storage temperature range	TJ, TSTG	-65 to +125			°C

Electrical Characteristics (TA = 25°C unless otherwise noted)

Parameter	Symbol	1N5817	1N5818	1N5819	Unit
* Maximum instantaneous forward voltage at 1.0 (Note 1)	VF	0.450	0.550	0.600	V
* Maximum instantaneous forward voltage at 3.1 (Note 1)	VF	0.750	0.875	0.900	V
* Maximum average reverse current TA = 25°C at rated DC blocking voltage (Note 1) TA = 100°C	I _R	1.0 10			mA
Typical junction capacitance at 4.0V, 1.0MHz	CJ	110			pF

^{*}JEDEC registered values

Notes: (1) Pulse test: $300\mu s$ pulse width, 1% duty cycle

⁽²⁾ Thermal resistance from junction to lead vertical P.C.B. mounted, 0.375" (9.5mm) lead length with 1.5 x 1.5" (38 x 38mm) copper pads



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0 0

20

Ratings and Characteristic Curves (TA = 25°C unless otherwise noted)

Fig. 1 - Forward Current Derating Curve 1.0 Resistive or Inductive Load 0.375" (9.5mm) Average Forward Current (A) ead Length 0.75 0.5 0.25

Fig. 3 - Typical Instantaneous Forward Characteristics

Case Temperature (°C)

80

100

120

140

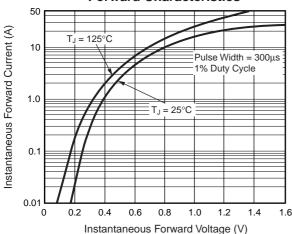


Fig. 5 - Typical Junction Capacitance 400 $T_J = 25^{\circ}C$ f = 1.0 MH_Z $V_{sig} = 50 \text{mVp-p}$ Junction Capacitance (pF) 100 10 0.1 100

Reverse Voltage (V)

Fig. 2 - Maximum Non-Repetitive Peak **Forward Surge Current**

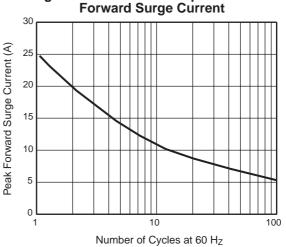
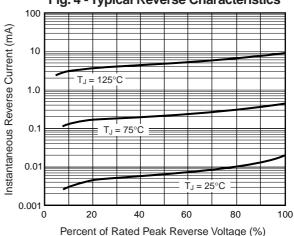
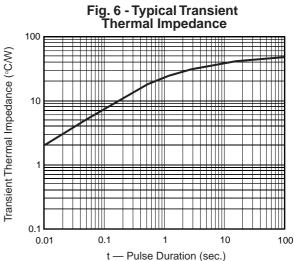


Fig. 4 - Typical Reverse Characteristics





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